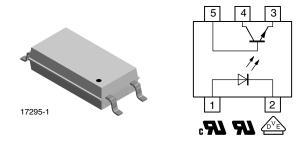


www.vishay.com

Vishay Semiconductors

Optocoupler, Phototransistor Output, SOP-6L5, 110 °C Rated, Half Pitch, Long Mini-Flat Package



DESCRIPTION

The TCLT111. series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 5-lead SOP-6L package.

APPLICATIONS

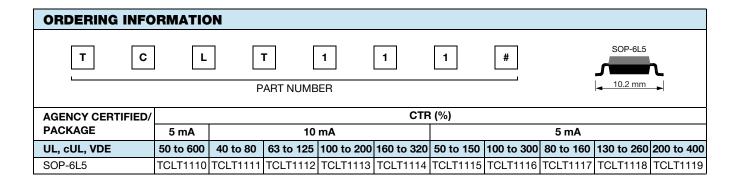
- Switchmode power supplies
- · Computer peripheral interface
- Microprocessor system interface

FEATURES

- SMD low profile 5 pin package
- Isolation test voltage 5000 V_{RMS}
- CTR flexibility available see order information
- Special construction
- Extra low coupling capacitance
- Connected base
- DC input with transistor output
- Temperature range 55 °C to 110 °C
- Creepage distance > 8 mm
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

AGENCY APPROVALS

- UL1577, file no. E76222
- cUL file no. E76222, equivalent to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1





ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V_{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
Isolation test voltage (RMS)		V _{ISO}	5000	V _{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	- 55 to + 110	°C			
Storage temperature range		T _{stg}	- 55 to + 125	°C			
Soldering temperature (1)		T _{sld}	260	°C			

Notes

⁽¹⁾ Wave soldering three cycles are allowed. Also refer to "Assembly Instruction" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V	
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j		50		pF	
OUTPUT							
Collector emitter voltage	I _C = 1 mA	V_{CEO}	70			V	
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V	
Collector emitter leakage current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		10	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V	
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		110		kHz	
Coupling capacitance	f = 1 MHz	C _k		0.3		pF	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
Maximum Rating for extended periods of the time can adversely affect reliability.



CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCLT1110	CTR	50		600	%
		TCLT1111	CTR	40		80	%
	V - 5 V I - 10 mA	TCLT1112	CTR	63		125	%
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	TCLT1113	CTR	100		200	%
		TCLT1114	CTR	160		320	%
		TCLT1111	CTR	13	30		%
l _O /l _F	$V_{CF} = 5 \text{ V}, I_{F} = 1 \text{ mA}$	TCLT1112	CTR	22	45		%
	V _{CE} = 5 V, I _F = 1 IIIA	TCLT1113	CTR	34	70		%
		TCLT1114	CTR	56	100		%
		TCLT1115	CTR	50		150	%
		TCLT1116	CTR	100		300	%
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCLT1117	CTR	80		160	%
		TCLT1118	CTR	130		260	%
		TCLT1119	CTR	200		400	%

SAFETY AND INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	1.6			kV	
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V_{IOTM}	8			kV	
lot test (sample test)	(see figure 2)	V_{pd}	1.3			kV	
	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω	
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω	
insulation resistance	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω	
Forward current		I _{si}	130			mA	
Power dissipation		P _{so}	265			mW	
Rated impulse voltage		V _{IOTM}	8			kV	
Safety temperature		T _{si}	150			°C	
Clearance distance			8.0			mm	
Creepage distance			8.0			mm	
Insulation distance (internal)			0.40			mm	

Note

• According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

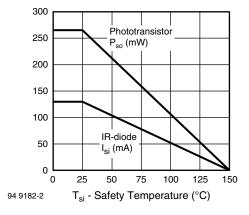


Fig. 1 - Derating Diagram

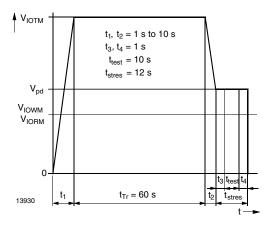


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5



SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _d		3		μs	
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _r		3		μs	
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _f		4.7		μs	
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _s		0.3		μs	
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _{on}		6		μs	
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{off}		5		μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{on}		9		μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{off}		10		μs	

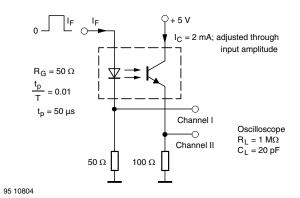


Fig. 3 - Test Circuit, Non-Saturated Operation

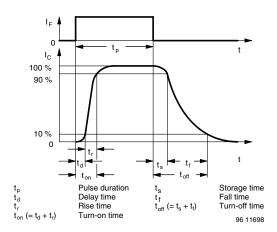


Fig. 5 - Switching Times

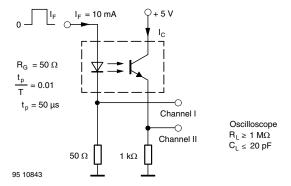
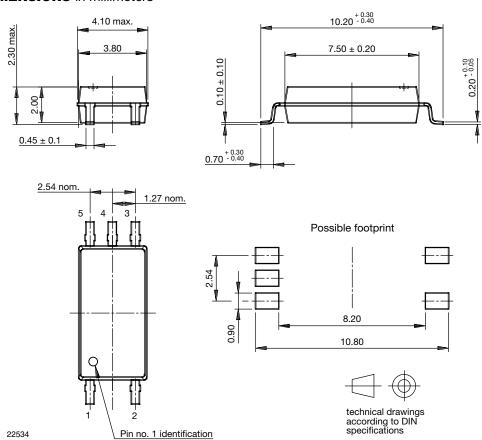


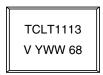
Fig. 4 - Test Circuit, Saturated Operation



PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING





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